

CONTENTS

| CHAPTER NO | TITLE | PAGE No. |
|------------|---|----------|
| | INTRODUCTION | 1 |
| | References | 8 |
| I | AMORPHOUS SEMICONDUCTORS | 9 |
| 1.1 | STRUCTURE OF AMORPHOUS SOLIDS | 9 |
| 1.1.1 | Solid State Theory | 9 |
| | A) General approach | |
| | B) Structure | |
| 1.1.2 | Studies of the structure of the Amorphous Materials. | 12 |
| 1.1.3 | Chemistry of covalent Amorphous Semiconductors. | 15 |
| 1.1.4 | Electronic Structure | 19 |
| 1.1.5 | Crystalline Solids | 21 |
| 1.1.6 | Effects of Disorder | 23 |
| 1.1.7 | Localized States. | 23 |
| 1.1.8 | Anderson Localization | 24 |
| 1.1.9 | Density of states | 25 |
| 1.1.10 | Mobility Edge | 30 |
| 1.1.11 | Band Models | 32 |
| 1.1.12 | Defects in Amorphous Solids | 35 |

| | | |
|--------|--|-----|
| 1.2 | TRANSPORT PROPERTIES | 42 |
| 1.2.1 | Electrical Properties of non-crystalline semiconductors. | 42 |
| 1.2.2 | D.C. Electrical Conductivity | 42 |
| 1.2.3 | Thermoelectric effect in Semiconductors | 52 |
| 1.2.4 | Seebeck effect and Thermoelectric Power. | 55 |
| 1.2.5. | Thermoelectric Power | 58 |
| 1.2.6 | Conduction by small-Polaron motion. | 61 |
| 1.2.7 | Switching | 64 |
| 1.3 | MAGNETIC PROPERTIES | 66 |
| 1.3.1 | Classification of Materials | 66 |
| 1.3.2 | Diamagnetism | 67 |
| 1.3.3 | Paramagnetism | 70 |
| | References | 71 |
| II | EXPERIMENTAL DETAILS | 74 |
| 2.1 | Preparation of Sample | 74 |
| 2.2 | X-ray study | 77 |
| 2.3 | Current Voltage characteristics | 79 |
| 2.4 | D.C. Electrical conductivity | 81 |
| 2.5 | Thermoelectric Power | 93 |
| 2.6 | Magnetic Susceptibility | 102 |
| | References | 110 |

| | | |
|-----|------------------------|-----|
| III | RESULTS AND DISCUSSION | 111 |
| | SUMMARY | 121 |
| | References | 124 |